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(54) **Chemical mechanical polishing for isolation dielectric planarization**

(57) A fabrication method for an integrated circuit structure, comprising the steps of: forming an oxide structure which includes, distributed there-through, a first layer comprising silicon and carbon; and polishing said oxide structure, using a slurry composition which has a selectivity to said first layer of greater than 10 to 1, so that said polishing step smoothly removes said oxide on a first side of said first layer and stops on exposed areas of said first layer; whereby said exposed areas of said first layer define a uniform surface level for said oxide structure. In an embodiment, silicon carbide is used for a hardmask for the isolation dielectric etch and also serves as an etch stop for chemical-mechanical polishing. Alternatively, silicon carbonitride or silicon carboxide can be used.

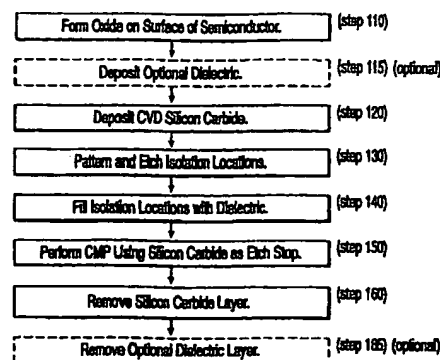


FIG. 1



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EUROPEAN SEARCH REPORT

Application Number
EP 98 31 0556

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A	* column 3; figures 1-3 *	7	

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			TECHNICAL FIELDS SEARCHED (Int.Cl.6)
			H01L
The present search report has been drawn up for all claims			
Place of search		Date of completion of the search	Examiner
THE HAGUE		19 October 1999	Szarowski, A
CATEGORY OF CITED DOCUMENTS			
X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document		T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document	

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**ANNEX TO THE EUROPEAN SEARCH REPORT
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This annex lists the patent family members relating to the patent documents cited in the above-mentioned European search report. The members are as contained in the European Patent Office EDP file on
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For more details about this annex : see Official Journal of the European Patent Office, No. 12/82

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